

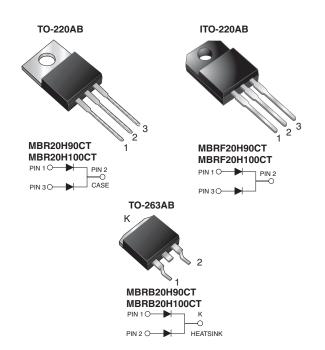
### MBR20HxxCT, MBRF20HxxCT, MBRB20HxxCT

Vishay General Semiconductor

RoHS

## **Dual Common Cathode High Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 10 A				
$V_{RRM}$	90 V to 100 V				
I <sub>FSM</sub>	250 A				
I <sub>R</sub>	4.5 μA				
V <sub>F</sub>	0.64				
T <sub>J</sub> max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Dual common cathode				

#### **FEATURES**

- Power pack
- · Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PARAMETER		SYMBOL	MBR20H90CT	MBR20H100CT	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	90	100		
Working peak reverse voltage		$V_{RWM}$	90	100	V	
Maximum DC blocking voltage		$V_{DC}$	90	100		
Maximum average forward rectified current	total device	_	20			
	per diode	I <sub>F(AV)</sub>	10			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	250		Α	
Peak repetitive reverse current per diode at $t_p = 2.0 \mu s$ , 1 kHz		I <sub>RRM</sub>	1.0			
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T <sub>J</sub> . T <sub>STG</sub>	-65 to +175		°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V <sub>AC</sub>	1500		V	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 10 A	T <sub>C</sub> = 25 °C	0.77	V	
		I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C	0.64		
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 25 °C	0.88		
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 125 °C	0.73		
Maximum reverse current at working peak reverse voltage per diode	I <sub>R</sub> <sup>(2)</sup>	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	4.5	μΑ	
			T <sub>J</sub> = 125 °C	6.0	mA	

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	5.8	2.0	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20H100CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF20H100CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB20H100CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB20H100CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR20H100CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF20H100CTHE3/45 1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB20H100CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB20H100CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

#### Note

(1) AEC-Q101 qualified

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

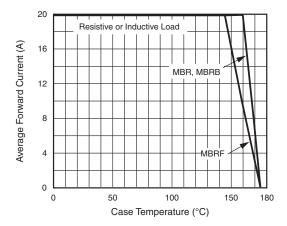


Fig. 1 - Forward Current Derating Curve

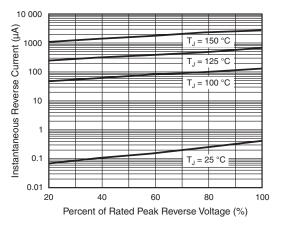


Fig. 4 - Typical Reverse Characteristics Per Diode

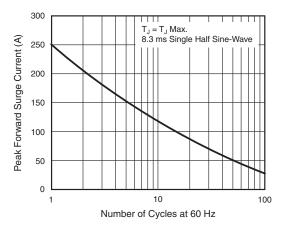


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

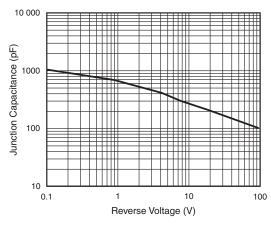


Fig. 5 - Typical Junction Capacitance Per Diode

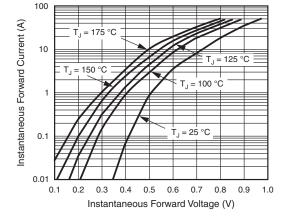


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

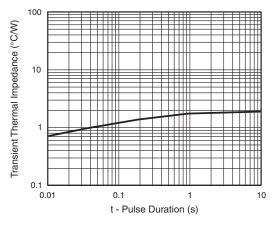


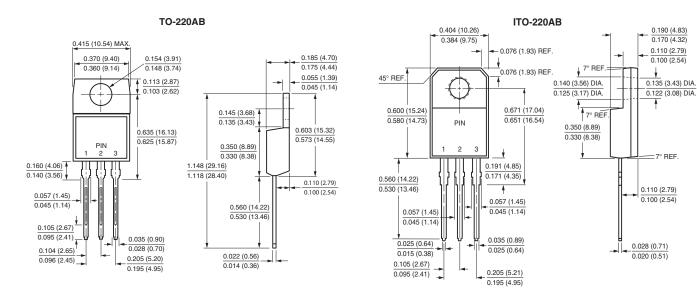
Fig. 6 - Typical Transient Thermal Impedance Per Diode

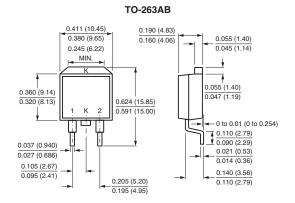


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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





# 0.42 (10.66) MIN. 0.33 (8.38) MIN. 0.670 (17.02) 0.591 (15.00) 0.15 (3.81) MIN. 0.08 (2.032) MIN.

0.095 (2.41)

**Mounting Pad Layout** 



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